TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC4051BP, TC4051BF, TC4051BFN, TC4051BFT TC4052BP, TC4052BF, TC4052BFN, TC4052BFT TC4053BP, TC4053BF, TC4053BFN, TC4053BFT

#### TC4051B

Single 8-Channel Multiplexer/Demultiplexer

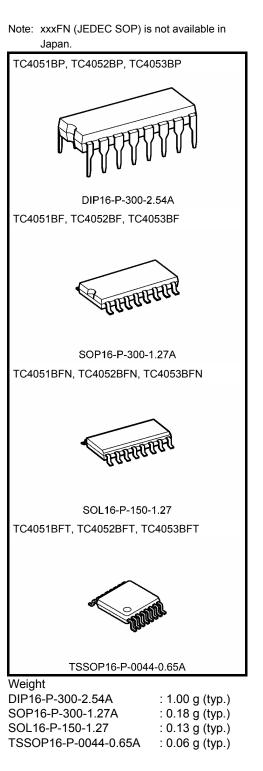
#### TC4052B

Differential 4-Channel Multiplexer/Demultiplexer

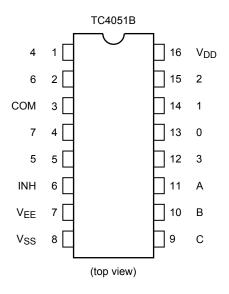
#### TC4053B

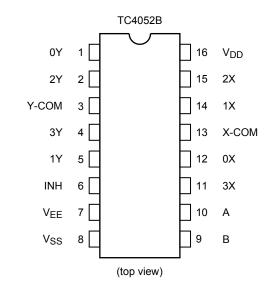
Triple 2-Channel Multiplexer/Demultiplexer

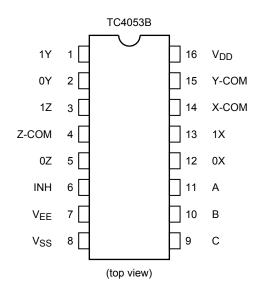
TC4051B, TC4052B and TC4053B are multiplexers with capabilities of selection and mixture of analog signal and digital signal. TC4051B has 8 channels configuration. TC4052B has 4 channel × 2 configuration and TC4053B has 2 channel × 3 configuration. The digital signal to the control terminal turns "ON" the corresponding switch of each channel, with large amplitude (V<sub>DD</sub> – V<sub>EE</sub>) can be switched by the control signal with small logical amplitude (V<sub>DD</sub> – V<sub>SS</sub>). For example, in the case of V<sub>DD</sub> = 5 V V<sub>SS</sub> = 0 V and V<sub>EE</sub> = -5 V, signals between -5 V and +5 V can be switched from the logical circuit with single power supply of 5 volts. As the ON-resistance of each switch is low, these can be connected to the circuits with low input impedance.



# **Pin Assignment**







# **Truth Table**

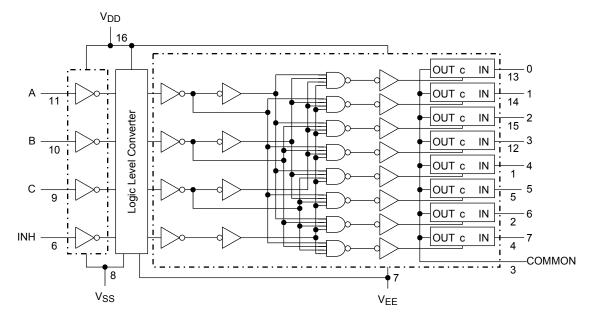
	Control	Inputs		"ON" Channel					
Inhibit	CΔ	В	А	TC4051B	TC4052B	TC4053B			
L	L	L	L	0	0X, 0Y	0X, 0Y, 0Z			
L	L	L	Н	1	1X, 1Y	1X, 0Y, 0Z			
L	L	Н	L	2	2X, 2Y	0X, 1Y, 0Z			
L	L	Н	Н	3	3X, 3Y	1X, 1Y, 0Z			
L	Н	L	L	4	—	0X, 0Y, 1Z			
L	Н	L	Н	5	—	1X, 0Y, 1Z			
L	Н	Н	L	6	—	0X, 1Y, 1Z			
L	Н	Н	Н	7	—	1X, 1Y, 1Z			
Н	Х	Х	Х	None	None	None			

X: Don't care

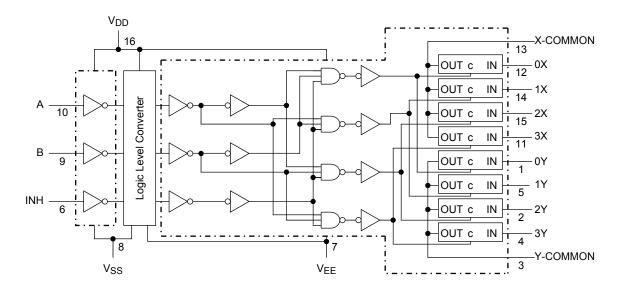
Δ: Except TC4052B

## Logic Diagram

TC4051B

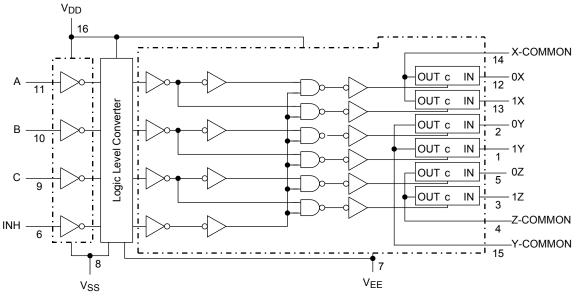


## TC4052B



#### TC4053B

TOSHIBA



#### Truth Table

Control C	Impedance between IN-OUT	(Note)
Н	0.5 to 5 $\times$ 10 $^2$ $\Omega$	
L	>10 <sup>9</sup> Ω	

Note: See electrical characteristics

-OUT c IN

## Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
DC supply voltage	V <sub>DD</sub> -V <sub>SS</sub>	-0.5 to 20	V
DC supply voltage	V <sub>DD</sub> -V <sub>EE</sub>	-0.5 to 20	V
Control input voltage	V <sub>CIN</sub>	$V_{SS}{-}0.5$ to $V_{DD}{+}0.5$	V
Switch I/O voltage	V <sub>I</sub> /V <sub>O</sub>	$V_{\mbox{\scriptsize EE}}-0.5$ to $V_{\mbox{\scriptsize DD}}+0.5$	V
Control input current	ICIN	±10	mA
Potential difference across I/O during ON	VI-VO	-0.5 to 0.5	V
Power dissipation	PD	300 (DIP)/180 (SOIC)	mW
Operating temperature range	T <sub>opr</sub>	-40 to 85	°C
Storage temperature range	T <sub>stg</sub>	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

# **Operating Ranges (Note)**

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit	
DC supply voltage	V <sub>DD</sub> -V <sub>SS</sub>		3	_	18	V	
DC supply voltage	V <sub>DD</sub> -V <sub>EE</sub>		3	_	18	v	
Control input voltage	V <sub>IN</sub>		$V_{SS}$	_	V <sub>DD</sub>	V	
Input/output voltage	V <sub>IN</sub> /V <sub>OUT</sub>	_	$V_{EE}$		V <sub>DD</sub>	V	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused Control inputs must be tied to either  $V_{DD}$  or  $V_{SS}$ .

## **Static Electrical Characteristics**

		Test Condition				-40	0°C		25°C	_	85°C		
Characteristics	Symbol		V <sub>SS</sub> (V)	V <sub>EE</sub> (V)	V <sub>DD</sub> (V)	Min	Max	Min	Тур.	Max	Min	Max	Unit
Control input high voltage			V	Vee	5	3.5	_	3.5	2.75	—	3.5	_	
	VIH		$V_{EE} = V_{SS}$ R <sub>L</sub> = 1 k $\Omega$		10	7.0		7.0	5.50	—	7.0	—	V
		$V_{IS} = V_{DD}$	to V <sub>S</sub>	S S	15	11.0		11.0	8.25		11.0		
Control input low		thru 1 kΩ	I <sub>IS</sub> < 2	2 μΑ	5	—	1.5	—	2.25	1.5	—	1.5	
Control input low voltage	VIL		on all chanr		10	—	3.0	—	4.5	3.0	_	3.0	V
				1	15	_	4.0		6.75	4.0		4.0	
On state		$0 \le V_{IS} \le V_{DD}$	0	0	5	—	850	—	240	950	_	1200	
On-state resistance	R <sub>ON</sub>	$R_L = 10 k\Omega$	0	0	10	—	210	—	110	250	_	300	Ω
			0	0	15	_	140		80	160	_	200	
∆On-state	R <sub>ON</sub> ∆	_	0	0	5	—		—	10	—			
resistance between any 2			0	0	10	—		—	6	—			Ω
switches			0	0	15	—	—		4	—	_	—	
Input/output	I <sub>OFF</sub>	V <sub>IN</sub> = 18 V, V <sub>OUT</sub> = 0 V V <sub>IN</sub> = 0 V, V <sub>OUT</sub> = 18 V			18	—	±100	—	±0.01	±100		±1000	nA
leakage current					18	_	±100	_	±0.01	±100		±1000	
	I <sub>DD</sub>		(Note)		5	—	5.0	—	0.005	5.0	—	150	
Quiescent supply current		$V_{IN}=V_{SS},\ V_{DD}$			10	—	10	—	0.010	10	—	300	μA
					15	_	20	_	0.015	20		600	
Input current	I <sub>IN</sub>	$V_{IH} = 18 V$ $V_{IL} = 0 V$			18	—	0.1	—	10 <sup>-5</sup>	0.1	—	1.0	μA
input current					18	_	-0.1	_	-10 <sup>-5</sup>	-0.1		-1.0	μА
Input capacitance	C <sub>IN</sub>				_	_		_	5	7.5			pF
Switch input capacitance	C <sub>IN</sub>	—			_	—	_	—	10	_	—	—	pF
		TC4051B TC4052B		10	_	_	_	58	_		_		
Output capacitance	COUT			10	—	—	—	30	—	—	—	pF	
		TC4053B			10	—		—	17	—	_		
		TC4051B			10	_		_	0.2		_		
Feedthrough capacitance	C <sub>IN</sub> - C <sub>-OUT</sub>	TC4052B		10	_		_	0.2	—	_		pF	
		TC4053B			10	—		_	0.2	_	_		

Note: All valid input combinations.

# Dynamic Electrical Characteristics (Ta = 25°C, C<sub>L</sub> = 50 pF)

		Test Condition								
Characteristics	Symbol		V <sub>SS</sub> (V)	V <sub>EE</sub> (V)	V <sub>DD</sub> (V)	Min	Тур.	Max	Unit	
				0	0	5	_	15	45	
Phase difference between input to output	<b>ф</b> І-О			0	0	10	—	8	20	ns
			0	0	15	_	6	15		
	t			0	0	5	—	170	550	
Propagation delay time	t <sub>pZL</sub>			0	0	10	—	90	240	
(A, B, C, -OUT)	t <sub>pZH</sub>	$R_L = 1 \ k\Omega$		0	0	15	—	70	160	ns
(A, B, C, -001)	t <sub>pLZ</sub>			0	-5	5	—	100	240	
	t <sub>pHZ</sub>			0	-7.5	7.5	—	80	160	
				0	0	5	—	120	380	
Propagation dolay time	+			0	0	10	—	60	200	ns
Propagation delay time	t <sub>pZL</sub> t <sub>pZH</sub>	$R_L = 1 \ k\Omega$		0	0	15	—	50	160	
(INH-OUT)				0	-5	5	—	80	200	
				0	-7.5	7.5	—	60	160	
	t <sub>pLZ</sub> t <sub>pHZ</sub>			0	0	5	_	170	450	
Propagation delay time				0	0	10	—	90	210	
		$R_L = 1 \ k\Omega$		0	0	15	—	70	160	ns
(INH-OUT)				0	-5	5	—	100	210	
				0	-7.5	7.5	—	80	160	
-3dB cutoff frequency				-5	-5	5		20		
TC4051B	f <sub>max</sub> (I-O)	$R_L = 1 k\Omega$	(Note 1)		_5 _5	5		30		MHz
TC4052B	Imax (I-O)			-5 -5	-5 -5	5	_	40		
TC4053B				-5	-5	5		40		
		R <sub>L</sub> = 10 kΩ		-2.5	-2.5	2.5	—	0.15	—	
Total harmonic distortion	—	f = 1  kHz	(Nata 0)	-5	-5	5	—	0.03	—	%
			(Note 2)	-7.5	-7.5	7.5	_	0.02	—	
-50dB feedthrough		$R_L = 1 k\Omega$	(Note 3)	-5	-5	5	_	500		kHz
(switch off)	_	$\Gamma L = 1 K S 2$	(Note 3)	-5	-5	5	_	500		NI IZ
Crosstalk	_	$R_L = 1 \ k\Omega$	(Note 4)	-5	-5	5	_	1.5	_	MHz
Crosstalk	_	$R_{IN} = 1 \ k\Omega$		0	0	5	_	200	_	
Crosstalk		$R_{OUT} = 10 \ k\Omega$		0	0	10	—	400	—	mV
(control-OUT)		$C_L = 15 \text{ pF}$		0	0	15	—	600	—	

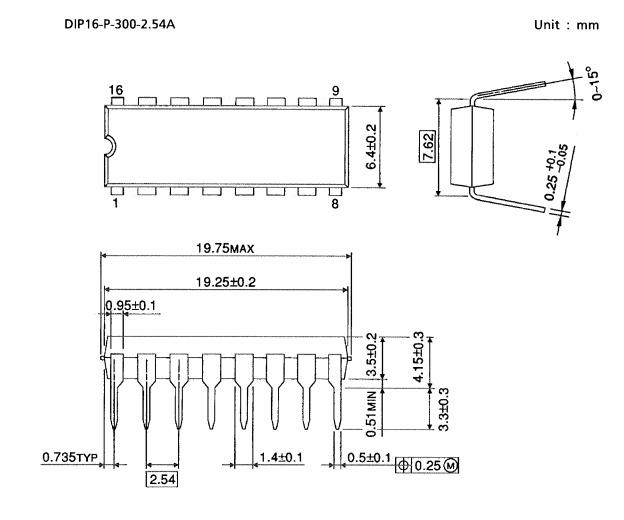
Note 1: Sine wave of  $\pm 2.5 V_{p-p}$  shall be used for  $V_{is}$  and the frequency of 20 log 10  $\frac{V_{OS}}{V_{is}} = -3dB$  shall be f<sub>max</sub>.

Note 2: V<sub>is</sub> shall be sine wave of 
$$\pm \left(\frac{V_{DD} - V_{EE}}{4}\right)$$
 p-p.

Note 3: Sine wave of  $\pm 2.5 \text{ V}_{p-p}$  shall be used for V<sub>is</sub> and the frequency of 20 log 10  $\frac{\text{V}_{OS}}{\text{V}_{is}} = -50 \text{dB}$  shall be feed-through.

Note 4: Sine wave of  $\pm 2.5 V_{p-p}$  shall be used for  $V_{is}$  and the frequency of 20 log 10  $\frac{V_{OS}}{V_{is}} = -50 dB$  shall be crosstalk.

## **Package Dimensions**



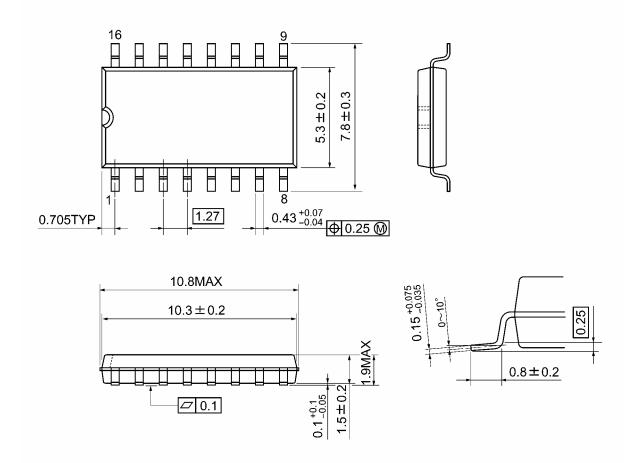
Weight: 1.00 g (typ.)



## **Package Dimensions**

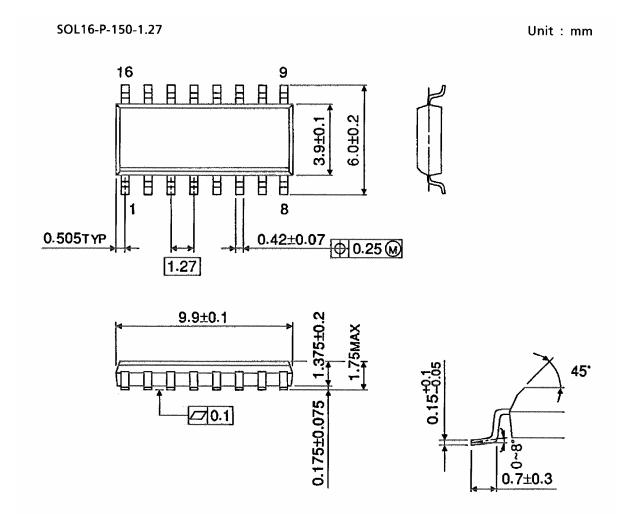
SOP16-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

# Package Dimensions (Note)



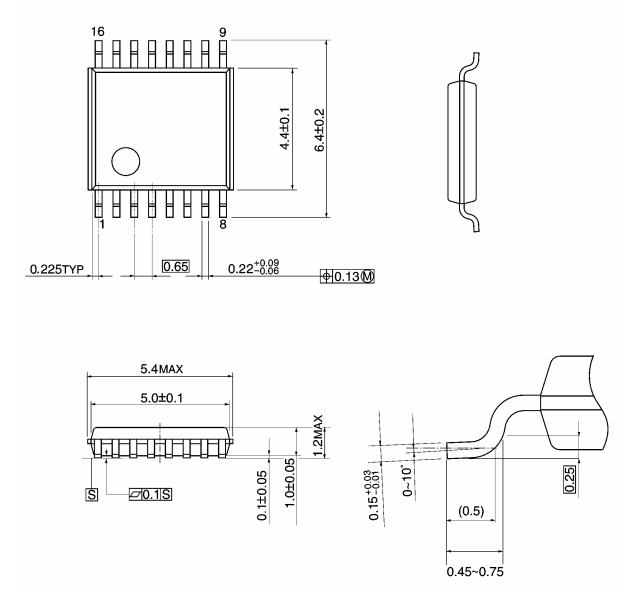
Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

# Package Dimensions

TSSOP16-P-0044-0.65A

Unit: mm



Weight: 0.06 g (typ.)

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20070701-EN

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